## PATENT CLAIMS

A converter circuit for switching a large number switching voltage levels, having n which 5 switching groups  $(1.1, \ldots,$ 1.n) provided for each phase (R, Y, B), with the n-th first switching group (1.n) being formed by a first power semiconductor switch (2) and a second power semiconductor switch (3), and with the first 10 switching group (1.1) to the switching group (1.(n-1)) each being formed by a first power semiconductor switch (2) and a second power semiconductor switch (3) and by a capacitor (4), which is connected to the first and second 15 power semiconductor switches (2, 3), with each of the n first switching groups (1.1, ..., 1.n) being connected in series to the respectively adjacent first switching group (1.1, ..., 1.n), and with the first and the second power semiconductor switches (2, 3) in the first first switching group 20 (1.1)being connected to one another, characterized in that  $n \ge 1$  and p second switching groups (5.1, ..., 5.p) and p third switching groups (6.1, ..., 25 6.p) are provided, which are each formed by a first power semiconductor switch (2) and a second power semiconductor switch (3) and by a capacitor (4) which is connected to the first and second power semiconductor switches (2, 3), where  $p \ge 1$ 30 and each of the p second switching groups (5.1, 5.p) is connected in series with respectively adjacent second switching group (5.1, 5.p), and each of the p third switching groups (6.1, ..., 6.p) is connected in series with 35 the respectively adjacent third switching group (6.1, ..., 6.p), and the first second switching group (5.1) is connected to the first power

switch (2) semiconductor in the n-th first group switching (1.n), and the first third switching group (6.1) is connected to the second power semiconductor switch (3) in the n-th first switching group (1.n), and in that the capacitor (4) in the p-th second switching group (5.p) is connected in series with the capacitor (4) in the p-th third switching group (6.p).

10

15

5

2. The converter circuit as claimed in claim 1. characterized in that a voltage limiting network (7) is connected in parallel with the first power semiconductor switch (2) in the n-th switching group (1.n), and that voltage limiting network (7) is connected parallel in with the second semiconductor switch (3) in the n-th

20

- 3. The converter circuit as claimed in claim 2, characterized in that the voltage limiting network (7) has a capacitor.
- 25 4. The converter circuit as claimed in claim 2, characterized in that the voltage limiting network (7) has a series circuit formed by a resistor with a capacitor.

switching group (1.n).

30 5. The converter circuit as claimed in claim characterized in that the n-th first switching group (1.n) has a capacitor (4) which is connected the first and second power semiconductor switches (2, 3) in the n-th first switching group 35 (1.n), with the first second switching group (5.1) being connected to the capacitor (4) in the n-th first switching group (1.n), and with the first

third switching group (6.1) being connected to the capacitor (4) in the n-th first switching group (1.n).

- The converter circuit as claimed in one of claims 5 6. 1 to 4, characterized in that the first and second power semiconductor switches (2, 3) in the first second switching group (5.1) are connected to one another, with the junction point of the first and 10 second power semiconductor switches (2, 3) in the first second switching group (5.1) being connected to the first power semiconductor switch (2) in the n-th first switching group (1.n), and in that the first and second power semiconductor switches (2, 15 in the first third switching group (6.1) are connected to one another, with the junction point second power the first and semiconductor switches (2, 3) in the first third switching group being connected to the second power 20 semiconductor switch (3) in the n-th first switching group (1.n).
- The converter circuit as claimed in claim 5, characterized in that the first and second power 25 semiconductor switches (2, 3) in the first second (5.1)switching group are connected one another, with the junction point of the first and second power semiconductor switches (2, 3) in the first second switching group (5.1) being connected 30 to the junction point of the capacitor (4) in the n-th first switching group (1.n) and the first power semiconductor switch (2) in the n-th first switching group (1.n), and in that the first and second power semiconductor 35 switches (2, 3) in the first third switching group (6.1) are connected to one another, with the

junction point of the first and second power

semiconductor switches (2, 3) in the first third switching group (6.1) being connected to the junction point of the capacitor (4) in the n-th first switching group (1.n) and the second power semiconductor switch (3) in the n-th first switching group (1.n).

8. The converter circuit as claimed in one of claims 1 to 7, characterized in that the total number of the n first switching groups (1.1, ..., 1.n) corresponds to the total number of the p second and third switching groups (5.1, ..., 5.p; 6.1, ..., 6.p).

5

25

- 15 9. The converter circuit as claimed in one of claims 1 to 7, characterized in that the total number of the n first switching groups (1.1, ..., 1.n) is less than the total number of the p second and third switching groups (5.1, ..., 5.p; 6.1, ..., 6.p).
  - 10. The converter circuit as claimed in one of claims 1 to 7, characterized in that the total number of the n first switching groups (1.1, ..., 1.n) is greater than the total number of the p second and third switching groups (5.1, ..., 5.p; 6.1, ..., 6.p).
- 11. The converter circuit as claimed in one of claims

  1 to 10, characterized in that the first power semiconductor switch (2) and the second power semiconductor switch (3) in each switching group (1.1, ..., 1.n; 5.1, ..., 5.p; 6.1, ..., 6.p) are in each case in the form of a bidirectional power semiconductor switch.
  - 12. The converter circuit as claimed in one of claims

1 to 10, characterized in that the first power semiconductor switch (2) in each first and in each second switching group (1.1, ..., 1.n; 5.1, ..., 5.p) is a bidirectional power semiconductor switch,

in that the second power semiconductor switch (3) in each first and in each third switching group (1.1, ..., 1.n; 6.1, ..., 6.p) is a bidirectional power semiconductor switch,

10 and

5

15

in that the second power semiconductor switch (3) in each second switching group (5.1, ..., 5.p) and the first power semiconductor switch (2) in each third switching group (6.1, ..., 6.p) are in each case in the form of a unidirectional power semiconductor switch.

- 13. The converter circuit as claimed in one of claims 1 to 10, characterized in that the first power 20 semiconductor switch (2) in each first and in each third switching group (1.1, ..., 1.n; 6.1, ..., 6.p) is a bidirectional power semiconductor switch,
- in that the second power semiconductor switch (3)
  in each first and in each second switching group
  (1.1, ...,1.n; 5.1, ..., 5.p) is a bidirectional
  power semiconductor switch, and
- in that the first power semiconductor switch (2) in each second switching group (5.1, ..., 5.p) and the second power semiconductor switch (3) in each third switching group (6.1, ..., 6.p) is a unidirectional power semiconductor switch.
- 14. The converter circuit as claimed in one of claims

  1 to 10, characterized in that the first power semiconductor switch (2) and the second power semiconductor switch (3) in each first switching

group (1.1, ..., 1.n) are in each case in the form of a bidirectional power semiconductor switch, and in that the first power semiconductor switch (2) and the second power semiconductor switch (3) in each second switching group (5.1, ..., 5.p) and in each third switching group (6.1, ..., 6.p) are in each case in the form of a unidirectional power semiconductor switch.

10 The converter circuit as claimed in one of claims 15. 11 to 14, characterized in that the bidirectional semiconductor switch power is formed by electronic component which be can driven carries current in only one direction, and by a 15 passive electronic component which is connected back-to-back in parallel with this, cannot be driven and carries current in only one direction.

5

- 16. The converter circuit as claimed in one of claims
  20 12 to 15, characterized in that the unidirectional
  power semiconductor switch is formed by a passive
  electronic component which cannot be driven and
  carries current in only one direction.
- 25 The converter circuit as claimed in one of the 17. preceding claims, characterized in that, case of the n first switching groups (1.1, ..., 1.n), the two first power semiconductor switches in respectively adjacent first switching 30 groups (1.1, ..., 1.n) are integrated in a module, and the two second power semiconductor switches (3) respectively adjacent first in switching groups (1.1, ..., 1.n) are integrated in a module.
- 35 18. The converter circuit as claimed in claim 17, characterized in that, in the case of the p second switching groups (5.1, ..., 5.p), the two first

power semiconductor switches (2) in respectively adjacent second switching groups  $(5.1, \ldots, 5.p)$ are integrated in a module, and the two second power semiconductor switches (3) in respectively adjacent second switching groups (5.1, ..., 5.p) are integrated in a module, and in that, in the case of the p third switching (6.1, ..., 6.p), the two first semiconductor switches (2) in respectively adjacent third switching groups (6.1, ..., 6.p) are integrated in a module, and the two second power semiconductor switches (3) in respectively adjacent third switching groups (6.1, ..., 6.p) are integrated in a module.

15

10

5

- 19. The converter circuit as claimed in one of claims 1 to 16, characterized in that, in the case of the n first switching groups (1.1, ..., 1.n) and in the case of the p second and third switching groups (5.1, ..., 5.p; 6.1, ..., 6.p), the first power semiconductor switch (2) and the second power semiconductor switch (3) are in each case integrated in a module.
- 25 20. The converter circuit as claimed in one of the preceding claims, characterized in that, if there are a plurality of phases (R, Y, B), the p-th second switching groups (5.p) for the phases (R, Y, B) are connected in parallel with one another, and the p-th third switching groups (6.p) for the phases (R, Y, B) are connected in parallel with one another.
- 21. The converter circuit as claimed in claim 20, characterized in that the capacitors (4) in the p-th second switching groups (5.p) for the phases (R, Y, B) are combined to form one capacitor, and

in that the capacitors (4) in the p-th third switching groups (6.p) for the phases (R, Y, B) are combined to form one capacitor.